

Pin Descriptions

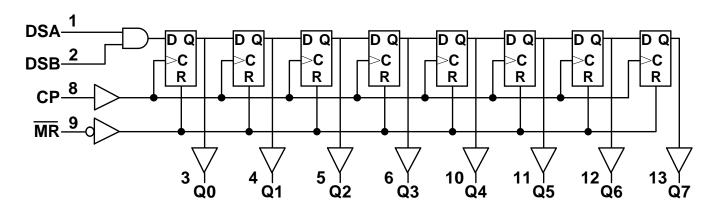
Pin Number	Pin Name	Function	
1	DSA	Serial Data Input	
2	DSB	Serial Data Input	
3	Q0	Data Output	
4	Q1	Data Output	
5	Q2	Data Output	
6	Q3	Data Output	
7	GND	Ground	
8	CP	Clock Pulse – Positive Edge Triggered	
9	MR	Master Reset - Asynchronous	
10	Q4	Data Output	
11	Q5	Data Output	
12	Q6	Data Output	
13	Q7	Data Output	
14	Vcc	Supply Voltage	

Function Table (Note 4)

M - 1-	Input				Output		
Mode	MR	СР	DSA	DSB	Q0	Q1-Q7	
Reset	L	Х	х	Х	L	L	
	н	Ť	L	Х	L	Qn←Qn-1 (n= 1 to7)	
Shift	н	Ť	Х	L	L	Qn←Qn-1 (n= 1 to7)	
	Н	↑	Н	Н	Н	Qn←Qn-1 (n= 1 to7)	

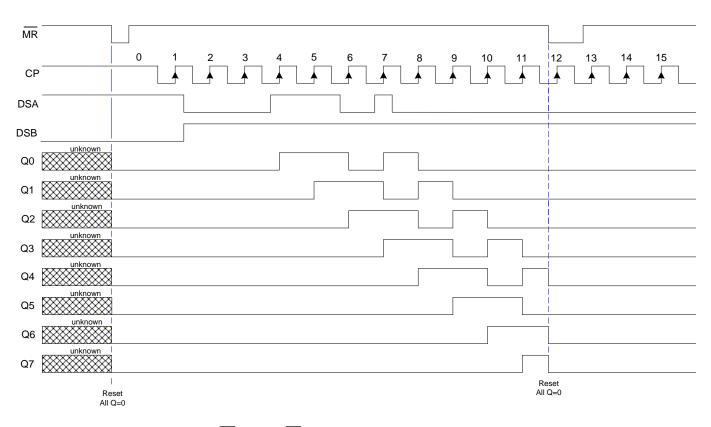
Note: 4. Signals asserted on DSA and DSB must be in place longer than Tsu (set-up time) before CP occurs and remain in place Thold (hold time) after CP.

Logic Diagram





Timing Diagram



Notes: 5. All Q values are reset to LOW when MR goes low. MR is asynchronous and overrides all other signals. 6. Serial data supplied at DSA and DSB is ANDED and transferred to Q0 on positive edge of CP.

Absolute Maximum Ratings (Note 7) (TA = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range (Note 8)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$	±20	mA
Ι _{ΟΚ}	Output Clamp Current $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	±20	mA
lo	Continuous Output Current -0.5V < Vo V _{CC} +0.5V	+/- 25	mA
lcc	Continuous Current through Vcc	50	mA
I _{GND}	Continuous Current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Notes: 7. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

8. Input Voltage cannot exceed Vcc to the extent the maximum clamp current is exceeded.



Recommended Operating Conditions (Note 9) (T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage	—	2.0	6.0	V
VI	Input Voltage	—	0	V _{CC}	V
Vo	Output Voltage	—	0	Vcc	V
	$V_{CC} = 2.0V$	—	625		
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 4.5V$	—	140	ns/V
		$V_{CC} = 6.0V$	—	85]
TA	Operating Free-Air Temperature	_	-40	+125	°C

Note: 9. Unused inputs should be held at $V_{\mbox{\scriptsize CC}}$ or Ground.

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Vcc	T _A = +25°C			T _A = -40°C to +85°C		T _A = -40°C	to +125°C	Unit
•		Conditions		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		—	2.0V	1.5	1.2		1.5	_	1.5		
VIH	High-level Input Voltage	—	4.5V	3.15	2.4	_	3.15	_	3.15	_	V
	voltage	—	6.0V	4.2	3.2		4.2		4.2		
		—	2.0V	_	0.8	0.5		0.5	_	0.5	
VIL	Low-level Input Voltage	—	4.5V	_	2.1	1.35		1.35	_	1.35	V
	vollage	_	6.0V	_	2.8	1.8	_	1.8	_	1.8	
		I _{OH} = -20μA	2.0V	1.9	2.0	_	1.9	_	1.9		
		I _{OH} = -20µА	4.5V	4.4	4.5	_	4.4	_	4.4		
V _{OH}	High-level Output Voltage	I _{OH} = -20μA	6.0V	5.9	6.0	_	5.9	_	5.9		V
	Output Voltage	I _{OH} = -4.0mA	4.5V	3.98	4.32		3.84		3.7		
		I _{OH} = -5.2mA	6.0V	5.48	5.81		5.34		5.2		
		I _{OL} = 20μΑ	2.0V		0	0.1	_	0.1	_	0.1	
		I _{OL} = 20μA	4.5V		0	0.1		0.1	_	0.1	
V _{OL}	Low-level Output Voltage	I _{OL} = 20μA	6.0V	_	0	0.1		0.1		0.1	V
	Oulput voltage	$I_{OL} = 4mA$	4.5V	_	0.15	0.26	_	0.33	_	0.4	1
		$I_{OL} = 5.2 \text{mA}$	6.0V		0.15	0.26		0.33		0.4	1
IJ	Input Current	V _I =GND or V _{CC}	6.0V			±0.1	_	± 1		± 1	μA
Icc	Supply Current	$V_I = GND \text{ or}$ $V_{CC}, I_O = 0A$	6.0V	_		8.0		80		160	μA



Switching Characteristics

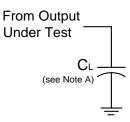
Symbol /		Test			T _A = +25°C		-40°C to	+85°C	-40°C to	o +125℃	Unit
Parameter	Pins	Conditions	Vcc	Min	Тур.	Max	Min	Max	Min	Max	
			2.0 V	6	23	_	5	_	4	_	
f _{MAX}	05	Figure 1	4.5 V	30	71	_	24		20	_	
Maximum Frequency	CP		5.0 V	_	78	_	_			_	MHz
riequency			6.0 V	35	85	_	28		24	—	
	CP		2.0 V	80	14	_	100		120	_	
	HIGH or	Figure 1	4.5 V	16	5	_	20		24		ns
	LOW		6.0 V	14	4	_	17		20	—	
t _w Pulse Width			2.0 V	60	17	_	75		90	_	
	MR LOW	Figure 1	4.5 V	12	6	_	15		18	—	ne
	WIT LOW	i igure i	6.0 V	10	5		13	_	15	_	ns
			2.0 V	60	8	_	75	_	90	_	
t _{SU}	DSA or	Figure 1	4.5 V	12	3		15		18	_	ns
Set-up Time	DSB to CP		6.0 V	10	2		13		15	_	
			2.0 V	4	-6		4		4	_	
t _н Hold Time	DSA or DSB to CP	Figure 1	4.5 V	4	-2		4		4		ns
Hold Time	D3D 10 CF		6.0 V	4	-2		4		4	_	
			2.0 V		41	170	_	215	—	255	
t _{PD}		Figure 1	4.5 V	_	15	34	—	43	—	51	
Propagation Delay	CP to Qn		5.0 V	_	12	_	_	_	_		ns
Delay			6.0 V		12	29	_	37	—	43	
			2.0 V	60	17		75		90	_	
t _{rec} Recovery Time	MR to CP		4.5 V	12	6	—	15		18	_	ns
Recovery fille			6.0 V	10	5		13		15	—	
t _{PHL}			2.0 V	_	39	140		175		210	
HIGH to LOW	MR to Qn	Figure 1	4.5 V		14	28		35		42	ns
Propagation	IVIR to Qn		5.0 V		11						115
Delay			6.0 V	—	11	24		30		36	
tτ			2.0 V		19	75		95		110	
Transition	All signals	Figure 1	4.5 V		7	15		19		22	ns
Time			6.0 V	_	6	13	_	16		19	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V _{CC} = 6V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	40	pF
CI	Input Capacitance	$V_I = V_{CC} - or GND$	3.5	pF

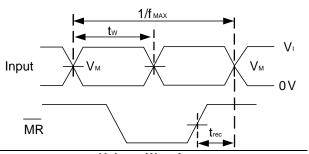


Parameter Measurement Information

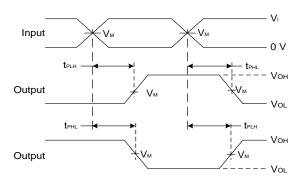


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V _{cc}	Inputs		V _M	CL
	Vi	t _r /t _f	, IAI	
2.0V	Vcc	6ns	V _{CC} /2	50pF
4.5V	V _{cc}	6ns	V _{CC} /2	50pF
5.0V	Vcc	6ns	V _{CC} /2	15pF
6.0V	V _{cc}	6ns	V _{CC} /2	50pF



Voltage Waveform Pulse Duration and Recovery Time

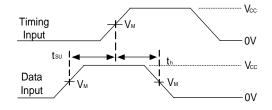


Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

A. Includes test lead and test apparatus capacitance. Notes:

- B. All pulses are supplied at pulse repetition rate ≤10 MHz.C. Inputs are measured separately, one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$
- E. Transition times $t_{t_i} t_{t_{ith_i}} t_{t_{ith_i}}$ are measured from the 10% to 90% or 90% to 10% of the appropriate waveform.

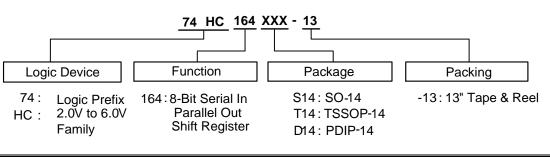
Figure 1 Load Circuit and Voltage Waveforms



Voltage Waveform Set-up and Hold Times



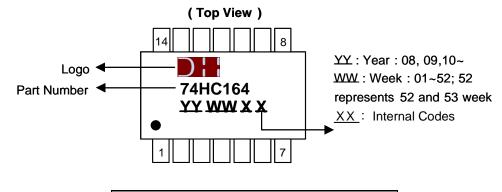
Ordering Information



Device	Package Code	Packaging	Pac	king
Device	Fackage Coue	Fackaying	Quantity	Part Number Suffix
74HC164S14-13	S14	SO-14	2,500/Tape & Reel	-13
74HC164T14-13	T14	TSSOP-14	2,500/Tape & Reel	-13
74HC164D14	D14	PDIP-14	TUBE	No Suffix

Marking Information

(1) SO-14, TSSOP-14, PDIP-14



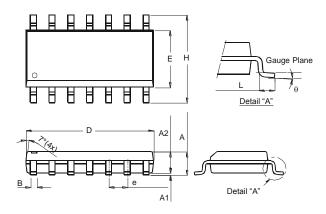
Part Number	Package
74HC164S14-13	SO-14
74HC164T14-13	TSSOP-14
74HC164D14	PDIP-14



Package Outline Dimensions (All dimensions in mm.)

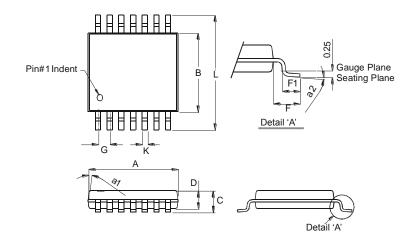
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

Package Type: SO-14



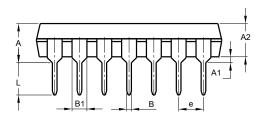
	SO-14	
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45	Тур
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27	Тур
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Di	mension	s in mm

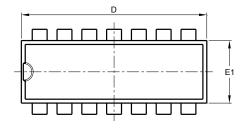
Package Type: TSSOP-14

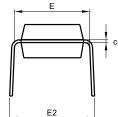


TSSOP-14			
Dim	Min	Max	
a1	7° (4X)		
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
С		1.2	
D	0.8	1.05	
F	1.00 Typ		
F1	0.45	0.75	
G	0.65 Тур		
K	0.19	0.30	
Ĺ	6.40 Тур		
All Dimensions in mm			

Package Type: PDIP-14







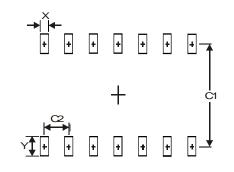
PDIP-14				
Dim	Min	Max		
Α	3.710	4.310		
A1	0.510	-		
A2	3.200	3.600		
В	0.380	0.570		
B1	1.524 (BSC)			
С	0.204	0.360		
D	18.800	19.200		
Е	6.200	6.600		
E1	7.320	7.920		
E2	8.400	9.000		
е	2.540 (BSC)			
L	3.000	3.600		
All Dimensions in mm				



Suggested Pad Layout

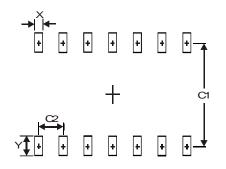
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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